

L Number	Hits	Search Text	DB	Time stamp
3	2486	"silicon carbide layer"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 10:36
4	128	"silicon carbide layer" and (nitrogen with dope\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 10:37
5	24	"silicon carbide layer" and (nitrogen with dope\$4) and (leakage near4 current)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 10:37
6	12	"silicon carbide layer" and (nitrogen with dope\$4) and (leakage near4 current) and "dielectric constant"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 10:38
-	2	("5800878").PN. or ((2001/0030369) or (2002/0027286) or (2001/0051445) or (2001/0031563)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:01
-	0	((("5800878").PN. or ((2001/0030369) or (2002/0027286) or (2001/0051445) or (2001/0031563)).CCLS.) and silicon and carbon and nitrogen	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:02
-	124	438/624.ccls. and silicon and carbon and nitrogen	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:02
-	28	438/624.ccls. and silicon and carbon and nitrogen and "inert gas"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:02
-	4	438/624.ccls. and silicon and carbon and nitrogen and "inert gas" and (electric with field)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:03
-	4	438/624.ccls. and silicon and carbon and nitrogen and "inert gas" and (electric with field) and energy	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:03
-	4	438/624.ccls. and silicon and carbon and nitrogen and "inert gas" and (electric with field) and energy and RF	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:03
-	4	438/624.ccls. and silicon and carbon and nitrogen and "inert gas" and (electric with field) and energy and RF and power	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:04
-	2	438/624.ccls. and silicon and carbon and nitrogen and "inert gas" and (electric with field) and energy and RF and power and electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:04
-	2	438/624.ccls. and silicon and carbon and nitrogen and "inert gas" and (electric with field) and energy and RF and power and electrode and plasma	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:04
-	1	438/624.ccls. and silicon and carbon and nitrogen and "inert gas" and (electric with field) and energy and RF and power and electrode and plasma and "silicon carbide"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:04
-	1	438/624.ccls. and silicon and carbon and nitrogen and "inert gas" and (electric with field) and energy and RF and power and electrode and plasma and "silicon carbide"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:13
-	4	438/624.ccls. and silicon and carbon and nitrogen and "inert gas" and (electric with field) and reaction	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/14 13:14

-	4	438/624.ccls. and silicon and carbon and nitrogen and "inert gas" and (electric with field) and reaction and RF	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 10:36
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